

## **Maximum Ratings** (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	75	V
Collector-Emitter Voltage	V <sub>CEO</sub>	40	V
Emitter-Base Voltage	V <sub>EBO</sub>	6	V
Collector Current - Continuous	Ic	600	mA
Peak Collector Current	Ісм	800	mA

### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P <sub>D</sub>	460	mW
Power Dissipation (Note 6)	P <sub>D</sub>	1	W
Thermal Resistance, Junction to Ambient (Note 5)	$R_{ hetaJA}$	272	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	$R_{ hetaJA}$	120	°C/W
Thermal Resistance, Junction to Lead (Note 7)	$R_{ heta JL}$	110	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

#### ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

- 5. For a device surface mounted on minimum recommended pad layout FR-4 PCB with single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition. The entire exposed collector pad is attached to the heatsink.

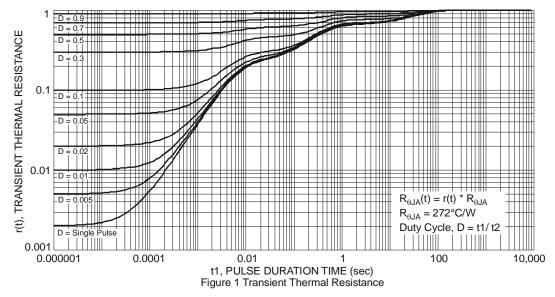
  6. Same as note 5, except device is surface mounted on 25mm X 25mm collector pad heatsink with 1oz copper.

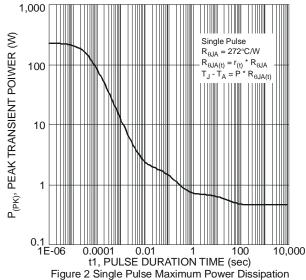
  7. Thermal resistance from junction to solder-point (at the end of the collector lead).

  8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



#### **Thermal Characteristics**





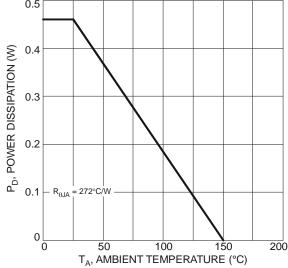


Figure 3 Power Dissipation vs. Ambient Temperature

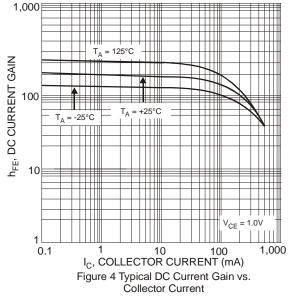


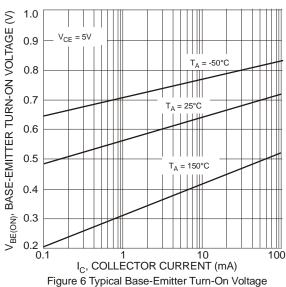
### **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS							
Collector-Base Breakdown Voltage	$BV_{CBO}$	75	_		V	$I_C = 100 \mu A, I_E = 0$	
Collector-Emitter Breakdown Voltage (Note 6)	$BV_{CEO}$	40	_		V	$I_C = 10 \text{mA}, I_B = 0$	
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	6	_		V	$I_E = 100 \mu A, I_C = 0$	
Collector Cutoff Current	I <sub>CEX</sub>			10	nA	$V_{CE} = 60V$ , $V_{EB(off)} = 3V$	
Collector Cutoff Current			_	10	nA	$V_{CB} = 60V, I_{E} = 0$	
Collector Cutoff Current	I <sub>CBO</sub>		_	10	μΑ	$V_{CB} = 60V, I_E = 0, T_A = +125$ °C	
Emitter Cutoff Current	I <sub>EBO</sub>	_	_	10	nA	$V_{EB} = 5V, I_{C} = 0$	
Base Cutoff Current	$I_{BL}$	_	_	20	nA	$V_{CE} = 60V$ , $V_{EB(off)} = 3V$	
ON CHARACTERISTICS (Note 6)							
		35	_		_	$V_{CE} = 10V, I_{C} = 0.1mA$	
		50	_	_	_	$V_{CE} = 10V$ , $I_C = 1mA$	
		75	_	_	_	$V_{CE} = 10V$ , $I_C = 10mA$	
DC Current Gain	$h_{FE}$	35	_		_	$V_{CE} = 10V, I_{C} = 10mA, T_{A} = -55^{\circ}C$	
		100	_	300	_	$V_{CE} = 10V, I_{C} = 150mA$	
		50	_	_	_	$V_{CE} = 1V, I_{C} = 150mA$	
		40		_	_	V <sub>CE</sub> = 10V, I <sub>C</sub> = 500mA	
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	_	_	0.3	V	$I_C = 150 \text{mA}, I_B = 15 \text{mA}$	
Concolor Ennior Caldidion Voltage				1.0	V	$I_C = 500 \text{mA}, I_B = 50 \text{mA}$	
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	0.6	_	1.2	V	$I_C = 150 \text{mA}, I_B = 15 \text{mA}$	
<u> </u>		_	_	2.0	•	$I_C = 500 \text{mA}, I_B = 50 \text{mA}$	
	SMALL SIGNAL CHARACTERISTICS (Note 6)						
Output Capacitance	C <sub>obo</sub>	_	_	8	pF	$V_{CB} = 10V, f = 1.0MHz, I_{E} = 0$	
Input Capacitance	C <sub>ibo</sub>			25	pF	$V_{EB} = 0.5V, f = 1.0MHz, I_{C} = 0$	
Current Gain-Bandwidth Product	f⊤	300		_	MHz	V <sub>CE</sub> = 20V, I <sub>C</sub> = 20mA, f = 100MHz	
Noise Figure	NF		_	4.0	dB	$V_{CE} = 10V$ , $I_{C} = 100\mu A$ , $R_{S} = 1.0k\Omega$ , $f = 1.0kHz$	
Input Impedance	h <sub>ie</sub>	0.25	_	1.25	kΩ	I <sub>C</sub> = 10mA, V <sub>CE</sub> = 10V, f = 1.0kHz	
Voltage Feedback Ratio	h <sub>re</sub>		_	4.0	X 10 <sup>-4</sup>		
Small-Signal Current Gain	h <sub>fe</sub>	75	_	375	_		
Output Admittance	h <sub>oe</sub>	25	_	200	μS		
SWICHING CHARACTERISTICS (Note 6)							
Delay Time	t <sub>d</sub>	_	_	10		$V_{CC} = 30V, V_{BE(off)} = -0.5V,$	
Rise Time	t <sub>r</sub>		_	25	nS	I <sub>C</sub> = 150mA, I <sub>B1</sub> = 15mA	
Storage Time	ts		_	225	110	$V_{CC} = 30V, I_C = 150mA,$	
Fall Time	t <sub>f</sub>	_	_	60		$I_{B1} = I_{B2} = 15 \text{mA}$	

Notes: 6. Measured under pulsed conditions. Pulse width  $\leq 300 \mu s$ . Duty cycle  $\leq 2\%$ .







vs. Collector Current

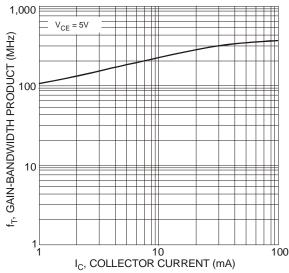


Figure 8 Typical Gain-Bandwidth Product vs. Collector Current

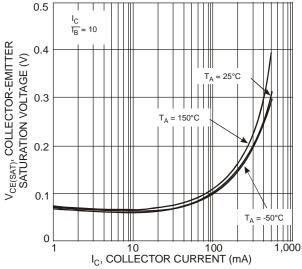
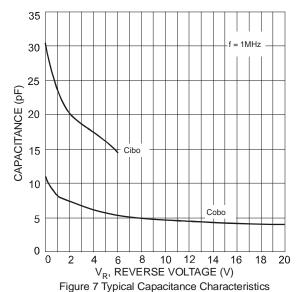


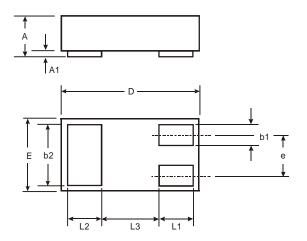
Figure 5 Typical Collector-Emitter Saturation Voltage vs. Collector Current



2.0  $I_C = 30 \text{mA}$ COLLECTOR-EMITTER VOLTAGE (V) 1.8 = 1mA $I_C = 10mA$ 1.6 I<sub>C</sub> = 100mA 1.4 I<sub>C</sub> = 300mA 1.2 1.0 8.0 0.6 0.4  $V_{CE}$ 0.2 0 0.1 1 I<sub>B</sub>, BASE CURRENT (mA) 0.001 100 Figure 9 Typical Collector Saturation Region

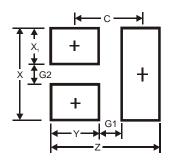


# **Package Outline Dimensions**



	X2-DFN1006-3				
Dim	Min	Max	Тур		
Α	_	0.40	_		
A1	0	0.05	0.03		
b1	0.10	0.20	0.15		
b2	0.45	0.55	0.50		
D	0.95	1.05	1.00		
E	0.55	0.65	0.60		
е	_	_	0.35		
L1	0.20	0.30	0.25		
L2	0.20	0.30	0.25		
L3	_	_	0.40		
All	All Dimensions in mm				

## **Suggested Pad Layout**



Dimensions	Value (in mm)
Z	1.1
G1	0.3
G2	0.2
Х	0.7
X1	0.25
Y	0.4
C	0.7



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